## Single crystal growth and magnetism of the novel $U_2RhIn_8$ compound

A. Bartha, M. Kratochvílová, V. Sechovský, and J. Custers 1

<sup>1</sup>Department of Condensed Matter Physics, Charles University, Ke Karlovu 5, 121 16 Prague

We report on the physical properties of the novel compound  $U_2RhIn_8$ . Single crystals have been prepared for the first time using In self-flux method. The compound adopts the  $Ho_2CoGa_8$ -type structure with lattice parameters a=4.6163 Å and c=12.0144 Å. In contrast to its nonmagnetic analog  $U_2RhGa_8$ ,  $U_2RhIn_8$  orders antiferromagnetically below  $T_N=117$  K with slightly enhanced Sommerfeld coefficient  $\gamma=47$  mJ.mol<sup>-1</sup>.K<sup>-2</sup>. The behavior of  $U_2RhIn_8$  strongly resembles that of related  $URhIn_5$  with respect to magnetization and resistivity. The susceptibility  $\chi(T)$  reveals strong anisotropy with effective magnetic moment corresponding roughly the free U ion. Additionally, an unusually large Curie temperature is found, reaching almost -800 K for  $H \mid\mid a$ . The weak temperature dependence of  $\chi(T)$  might be attributed to the mainly itinerant nature of 5f electrons. Magnetic field leaves the evolution of  $T_N$  unaffected up to 14T, but  $T_N$  is enhanced upon applying hydrostatic pressure. The overall phse diagram will be discussed in the context of magnetism in  $URhX_5$  and  $UX_3$  (X=In, Ga).